

# 2SA1908

Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC5100)

Application : Audio and General Purpose

**Absolute maximum ratings** (Ta=25°C)

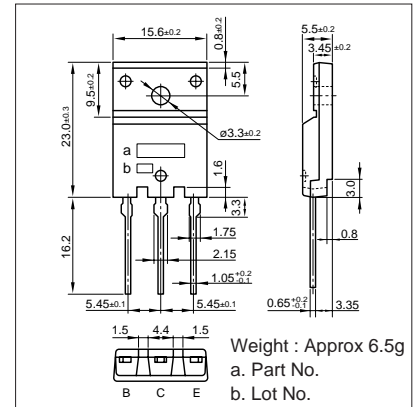
Symbol	Ratings	Unit
V <sub>CB0</sub>	-120	V
V <sub>CEO</sub>	-120	V
V <sub>EBO</sub>	-6	V
I <sub>C</sub>	-8	A
I <sub>B</sub>	-3	A
P <sub>C</sub>	75(T <sub>C</sub> =25°C)	W
T <sub>j</sub>	150	°C
T <sub>stg</sub>	-55 to +150	°C

**Electrical Characteristics** (Ta=25°C)

Symbol	Conditions	Ratings	Unit
I <sub>CB0</sub>	V <sub>CB</sub> =-120V	-10max	μA
I <sub>EBO</sub>	V <sub>EB</sub> =-6V	-10max	μA
V <sub>(BR)CEO</sub>	I <sub>C</sub> =-50mA	-120min	V
h <sub>FE</sub>	V <sub>CE</sub> =-4V, I <sub>C</sub> =-3A	50min*	
V <sub>CE(sat)</sub>	I <sub>C</sub> =-3A, I <sub>B</sub> =-0.3A	-0.5max	V
f <sub>T</sub>	V <sub>CE</sub> =-12V, I <sub>E</sub> =0.5A	20typ	MHz
COB	V <sub>CB</sub> =-10V, f=1MHz	300typ	pF

\*h<sub>FE</sub> Rank  $\bar{O}$ (50to 100), P(70to 140), Y(90to 180)

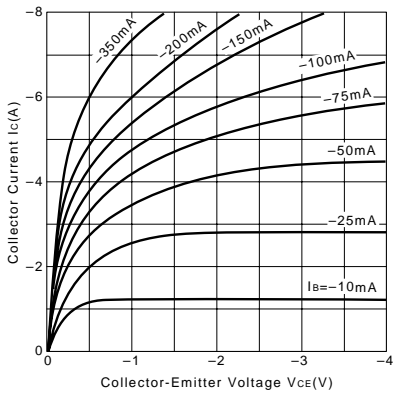
**External Dimensions FM100(TO3PF)**



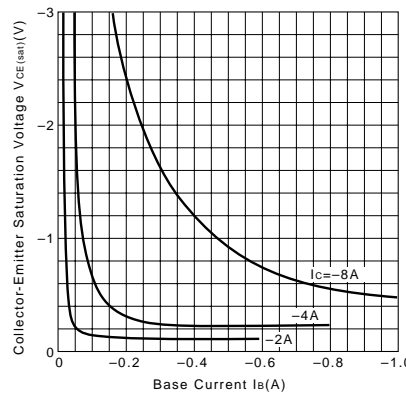
**Typical Switching Characteristics (Common Emitter)**

V <sub>CC</sub> (V)	R <sub>L</sub> (Ω)	I <sub>C</sub> (A)	V <sub>BB1</sub> (V)	V <sub>BB2</sub> (V)	I <sub>B1</sub> (A)	I <sub>B2</sub> (A)	t <sub>on</sub> (μs)	t <sub>stg</sub> (μs)	t <sub>f</sub> (μs)
-40	10	-4	-10	5	-0.4	0.4	0.14typ	1.40typ	0.21typ

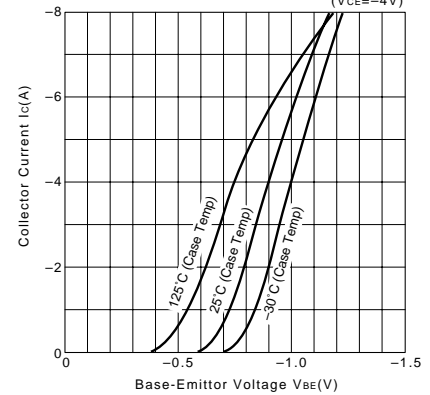
**I<sub>C</sub>-V<sub>CE</sub> Characteristics (Typical)**



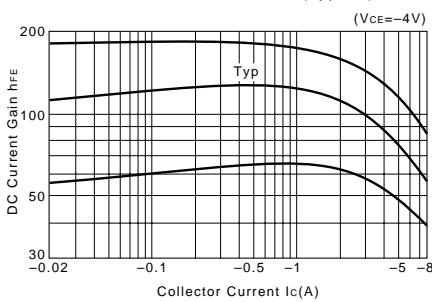
**V<sub>CE(sat)</sub>-I<sub>B</sub> Characteristics (Typical)**



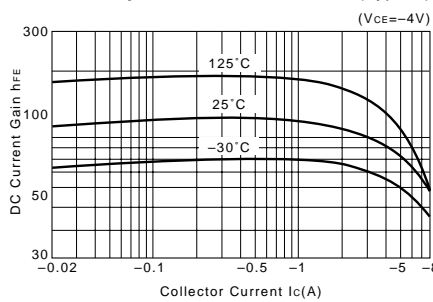
**I<sub>C</sub>-V<sub>BE</sub> Temperature Characteristics (Typical)**



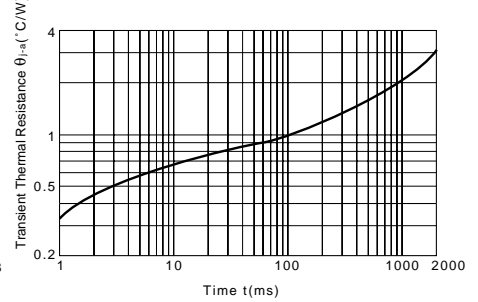
**h<sub>FE</sub>-I<sub>C</sub> Characteristics (Typical)**



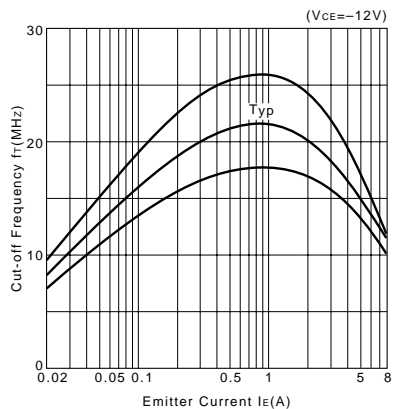
**h<sub>FE</sub>-I<sub>C</sub> Temperature Characteristics (Typical)**



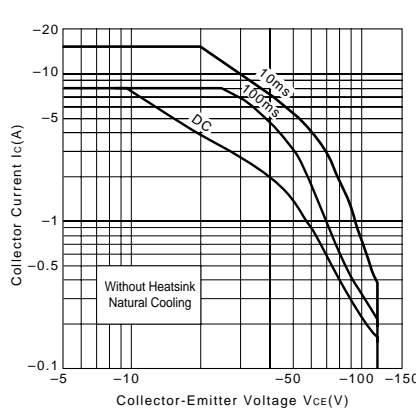
**θ<sub>j-a</sub>-t Characteristics**



**f<sub>T</sub>-I<sub>E</sub> Characteristics (Typical)**



**Safe Operating Area (Single Pulse)**



**P<sub>C</sub>-T<sub>a</sub> Derating**

